National Semiconductor

March 1988

MM54C42/MM74C42 BCD-to-Decimal Decoder

General Description

The MM54C42/MM74C42 one-of-ten decoder is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement transistors. This decoder produces a logical "0" at the output corresponding to a four bit binary input from zero to nine, and a logical "1" at the other outputs. For binary inputs from ten to fifteen all outputs are logical "1".

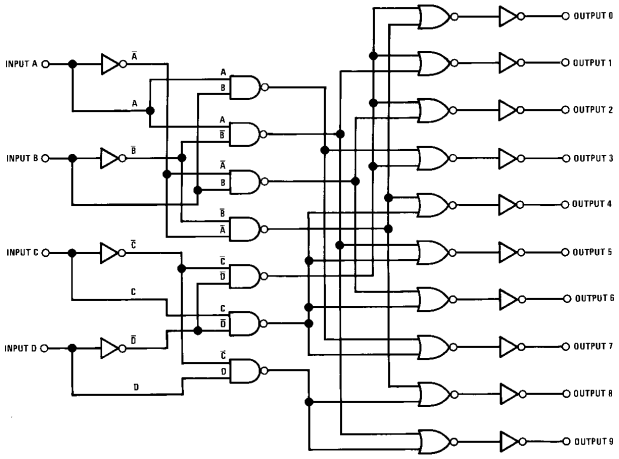
Features

- Supply voltage range — 3V to 15V
- Tenth power TTL compatible — drive 2 LPTTL loads
- High noise immunity — 0.45 V_{CC} (typ.)
- Low power — 50 nW (typ.)
- Medium speed operation — 10 MHz (typ.) with 10V V_{CC}

Applications

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Alarm systems
- Industrial electronics
- Remote metering
- Computers

Schematic Diagram



TL/F/5882–1

Truth Table

Inputs				Outputs									
D	C	B	A	0	1	2	3	4	5	6	7	8	9
0	0	0	0	0	1	1	1	1	1	1	1	1	1
0	0	0	1	1	0	1	1	1	1	1	1	1	1
0	0	1	0	1	1	0	1	1	1	1	1	1	1
0	0	1	1	1	1	1	0	1	1	1	1	1	1
0	1	0	0	1	1	1	1	0	1	1	1	1	1
0	1	0	1	1	1	1	1	1	0	1	1	1	1
0	1	1	0	1	1	1	1	1	1	0	1	1	1
0	1	1	1	1	1	1	1	1	1	1	0	1	1
1	0	0	0	1	1	1	1	1	1	1	1	0	1
1	0	0	1	1	1	1	1	1	1	1	1	1	0
1	0	1	0	1	1	1	1	1	1	1	1	1	1
1	0	1	1	1	1	1	1	1	1	1	1	1	1
1	1	0	0	1	1	1	1	1	1	1	1	1	1
1	1	0	1	1	1	1	1	1	1	1	1	1	1
1	1	1	0	1	1	1	1	1	1	1	1	1	1
1	1	1	1	1	1	1	1	1	1	1	1	1	1

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at Any Pin (Note 1)	−0.3V to V_{CC} + 0.3V
Operating Temperature Range	
MM54C42	−55°C to +125°C
MM74C42	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V_{CC} Range	3.0V to 15V
Absolute Maximum V_{CC}	18V
Lead Temperature (Soldering, 10 seconds)	260°C

DC Electrical Characteristics

Min/Max limits apply across temperature range unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
CMOS TO CMOS						
$V_{IN(1)}$	Logical "1" Input Voltage	V_{CC} = 5.0V	3.5			V
		V_{CC} = 10V	8.0			V
$V_{IN(0)}$	Logical "0" Input Voltage	V_{CC} = 5.0V			1.5	V
		V_{CC} = 10V			2.0	V
$V_{OUT(1)}$	Logical "1" Output Voltage	V_{CC} = 5.0V, I_O = −10 μA	4.5			V
		V_{CC} = 10V, I_O = −10 μA	9.0			V
$V_{OUT(0)}$	Logical "0" Output Voltage	V_{CC} = 5.0V, I_O = 10 μA			0.5	V
		V_{CC} = 10V, I_O = 10 μA			1.0	V
$I_{IN(1)}$	Logical "1" Input Current	V_{CC} = 15V, V_{IN} = 15V			1.0	μA
$I_{IN(0)}$	Logical "0" Input Current	V_{CC} = 15V, V_{IN} = 0V	−1.0			μA
I_{CC}	Supply Current	V_{CC} = 15V		0.05	300	μA
CMOS/LPTTL INTERFACE						
$V_{IN(1)}$	Logical "1" Input Voltage	54C, V_{CC} = 4.5V	V_{CC} − 1.5			V
		74C, V_{CC} = 4.75V	V_{CC} − 1.5			V
$V_{IN(0)}$	Logical "0" Input Voltage	54C, V_{CC} = 4.5V			0.8	V
		74C, V_{CC} = 4.75V			0.8	V
$V_{OUT(1)}$	Logical "1" Output Voltage	54C, V_{CC} = 4.5V, I_O = −360 μA	2.4			V
		74C, V_{CC} = 4.75V, I_O = −360 μA	2.4			V
$V_{OUT(0)}$	Logical "0" Output Voltage	54C, V_{CC} = 4.5V, I_O = 360 μA			0.4	V
		74C, V_{CC} = 4.75V, I_O = 360 μA			0.4	V
OUTPUT DRIVE (see 54C/74C Family Characteristics Data Sheet) T_A = 25°C (short circuit current)						
I_{SOURCE}	Output Source Current	V_{CC} = 5.0V, $V_{IN(0)}$ = 0V, V_{OUT} = 0V	−1.75			mA
I_{SOURCE}	Output Source Current	V_{CC} = 10V, $V_{IN(0)}$ = 0V, V_{OUT} = 0V	−8.0			mA
I_{SINK}	Output Sink Current	V_{CC} = 5.0V, $V_{IN(1)}$ = 5.0V, V_{OUT} = V_{CC}	1.75			mA
I_{SINK}	Output Sink Current	V_{CC} = 10V, $V_{IN(1)}$ = 10V, V_{OUT} = V_{CC}	8.0			mA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

AC Electrical Characteristics* $T_A = 25°C$, $C_L = 50$ pF, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t_{pd}	Propagation Delay Time to Logical "0" or "1"	$V_{CC} = 5.0V$		200	300	ns
		$V_{CC} = 10V$		90	140	ns
C_{IN}	Input Capacitance	(Note 2)		5		pF
C_{PD}	Power Dissipation Capacitance	(Note 3)		50		pF

*AC Parameters are guaranteed by DC correlated testing.

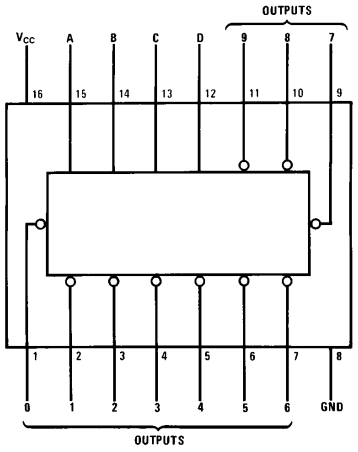
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Capacitance is guaranteed by periodic testing.

Note 3: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics Application Note—AN-90.

Connection Diagram

Dual-In-Line Package



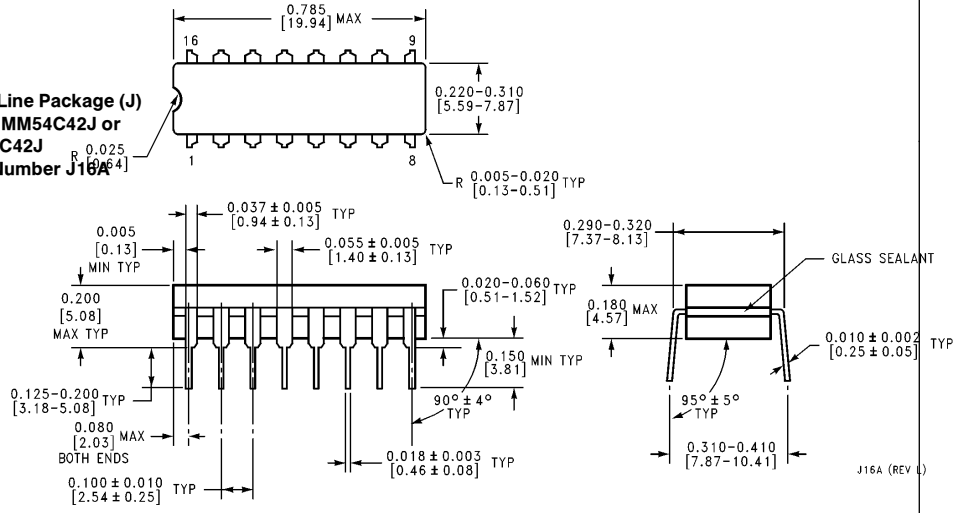
TL/F/5882–2

Top View

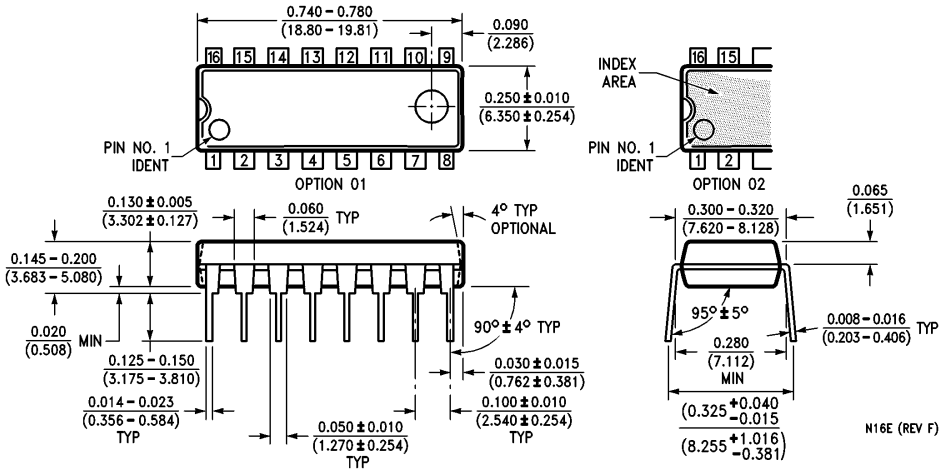
Order Number MM54C42 or MM74C42

Physical Dimensions inches (millimeters)

Ceramic Dual-In-Line Package (J)
Order Number MM54C42J or MM74C42J
NS Package Number J16A



Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N)
Order Number MM54C42N or MM74C42N
NS Package Number N16E

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

National Semiconductor Corporation
1111 West Bardin Road
Arlington, TX 76017
Tel: 1(800) 272-9959
Fax: 1(800) 737-7018

National Semiconductor Europe
Fax: (+49) 0-180-530 85 86
Email: cnjwge@tevm2.nsc.com
Deutsch Tel: (+49) 0-180-530 85 85
English Tel: (+49) 0-180-532 78 32
Français Tel: (+49) 0-180-532 93 58
Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408